

RJK5003DPD

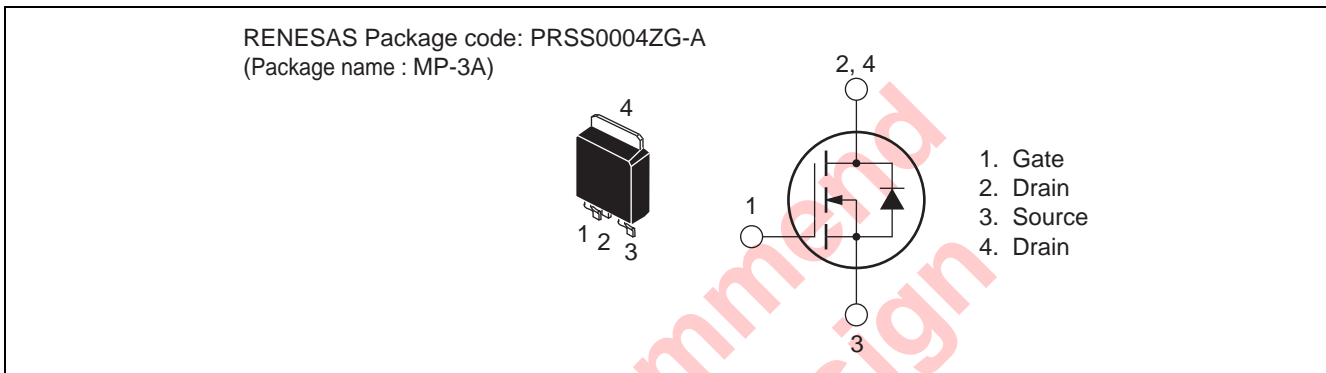
Silicon N Channel Power MOS FET
High Speed Power Switching Use

R07DS0049EJ0400
(Previous: REJ03G0580-0300)
Rev.4.00
Jul 22, 2010

Features

- V_{DSS} : 500 V
- $R_{DS(on)}$: 1.5 Ω (MAX.)
- I_D : 5 A
- Surface mount package (MP-3A)

Outline



Applications

- Lighting ballast, SMPS, etc.

Maximum Ratings

($T_c = 25^\circ\text{C}$)

Parameter	Symbol	Ratings	Unit	Conditions
Drain to source voltage	V_{DSS}	500	V	$V_{GS} = 0\text{ V}$
Gate to source voltage	V_{GSS}	± 30	V	$V_{DS} = 0\text{ V}$
Drain current	I_D	5	A	
Drain Peak current	$I_{D(pulse)}$ ^{Note1}	20	A	
Avalanche current	I_{AP}	5	A	$L = 200\ \mu\text{H}$
Channel dissipation	P_{ch}	62.5	W	
Channel temperature	T_{ch}	150	$^\circ\text{C}$	
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$	
Channel to case thermal impedance	θ_{ch-c}	2.0	$^\circ\text{C/W}$	Channel to case

Note: 1. Pulse width limited by safe operating area.

Electrical Characteristics

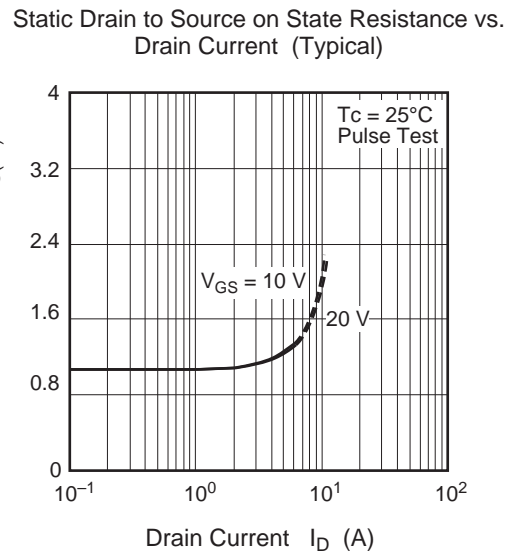
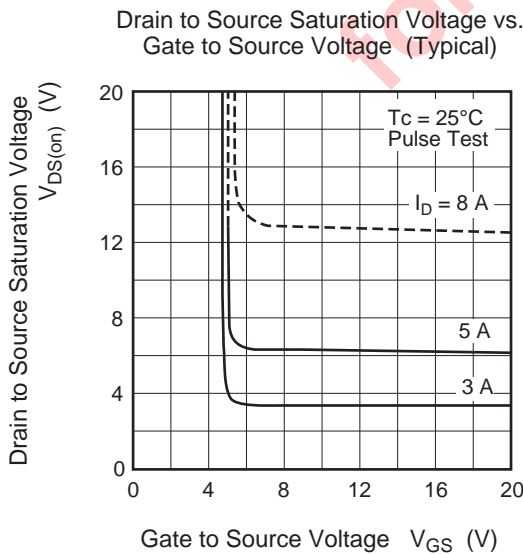
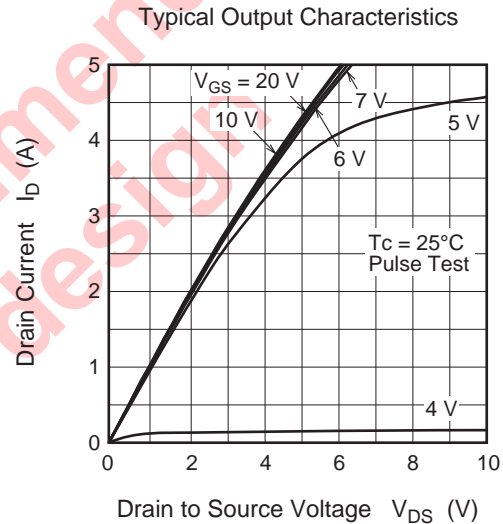
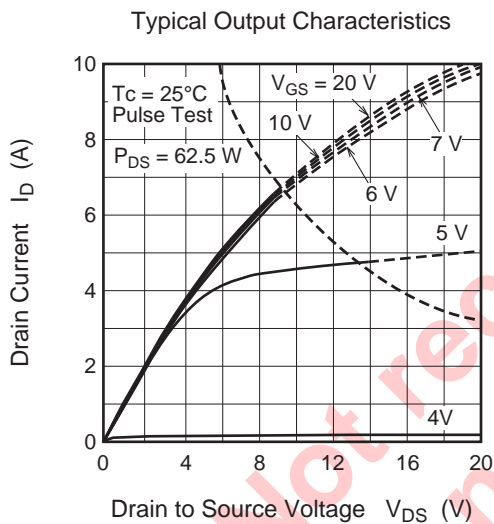
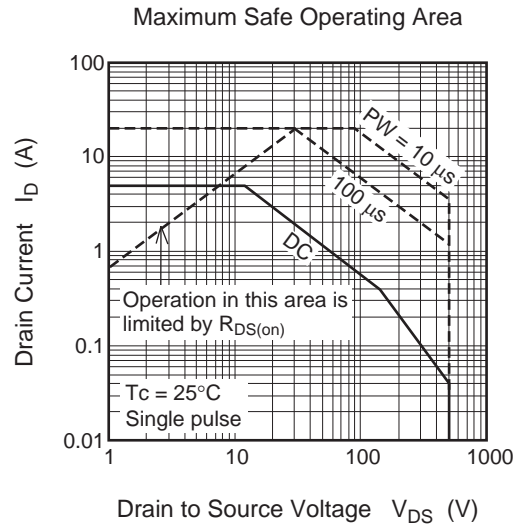
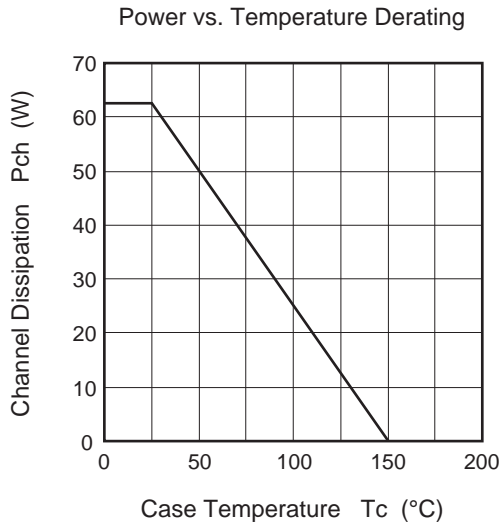
(Tch = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	500	—	—	V	$I_D = 1 \text{ mA}$, $V_{GS} = 0 \text{ V}$
Zero gate voltage drain current	I_{DSS}	—	—	1	mA	$V_{DS} = 500 \text{ V}$, $V_{GS} = 0 \text{ V}$
Gate to source leak current	I_{GSS}	—	—	± 0.1	μA	$V_{GS} = \pm 30 \text{ V}$, $V_{DS} = 0 \text{ V}$
Gate to source cutoff voltage	$V_{GS(off)}$	3.0	3.5	4.0	V	$I_D = 1 \text{ mA}$, $V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	1.3	1.5	Ω	$I_D = 2 \text{ A}$, $V_{GS} = 10 \text{ V}$ ^{Note2}
Input capacitance	C_{iss}	—	550	—	pF	$V_{DS} = 25 \text{ V}$, $V_{GS} = 0 \text{ V}$, $f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	60	—	pF	
Reverse transfer capacitance	C_{rss}	—	10	—	pF	
Turn-on delay time	$t_{d(on)}$	—	20	—	ns	$V_{DD} = 200 \text{ V}$, $I_D = 2 \text{ A}$, $V_{GS} = 10 \text{ V}$, $R_G = 25 \Omega$
Rise time	t_r	—	20	—	ns	
Turn-off delay time	$t_{d(off)}$	—	60	—	ns	
Fall time	t_f	—	25	—	ns	
Body-drain diode forward voltage	V_{DF}	—	1.0	1.5	V	$I_F = 2 \text{ A}$, $V_{GS} = 0 \text{ V}$ ^{Note2}

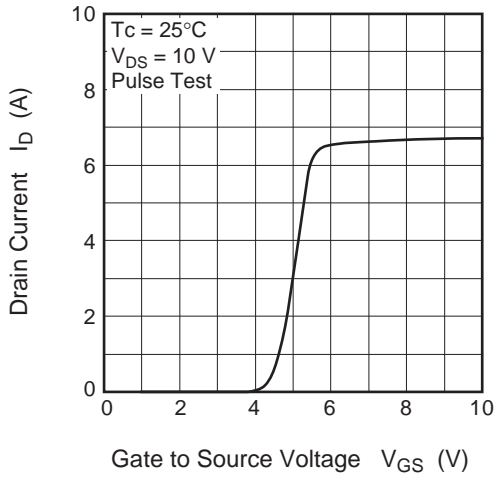
Note: 2. Pulse test

Not recommended
for new design

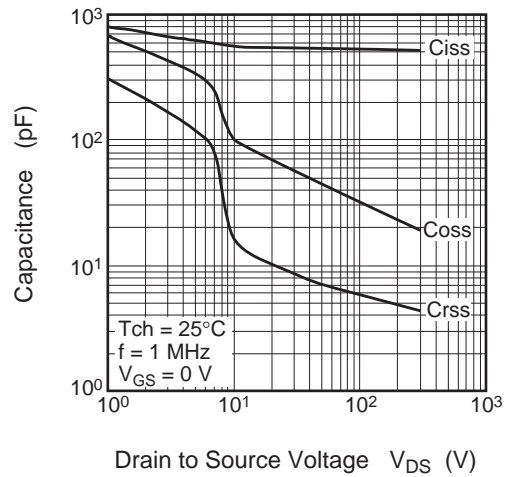
Main Characteristics



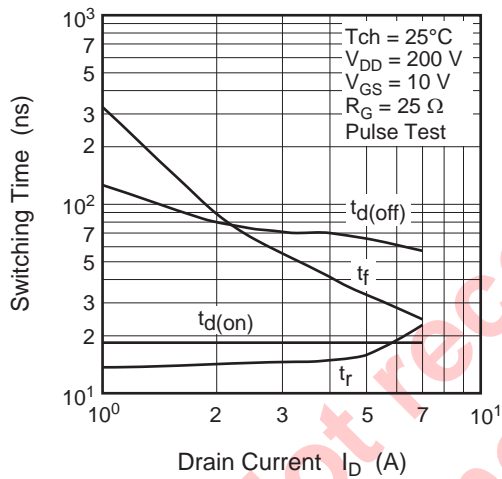
Transfer Characteristics (Typical)



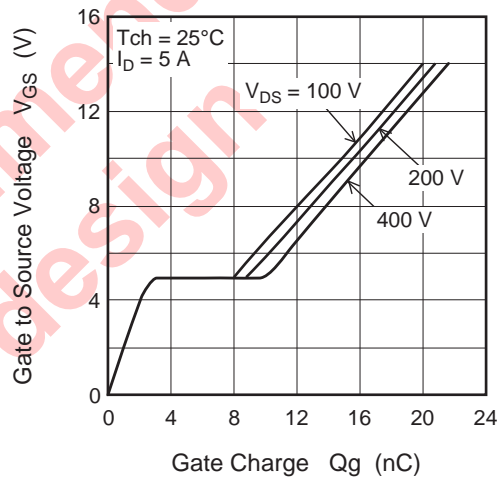
Capacitance vs. Drain to Source Voltage (Typical)



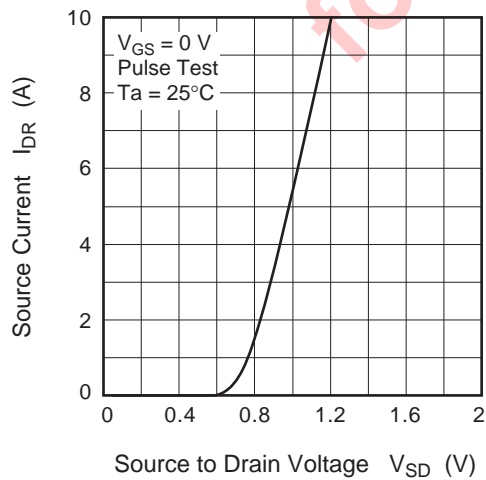
Switching Characteristics (Typical)



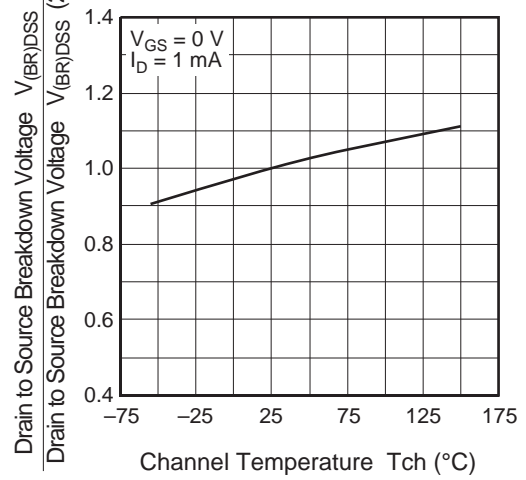
Gate to Source Voltage vs. Gate Charge (Typical)

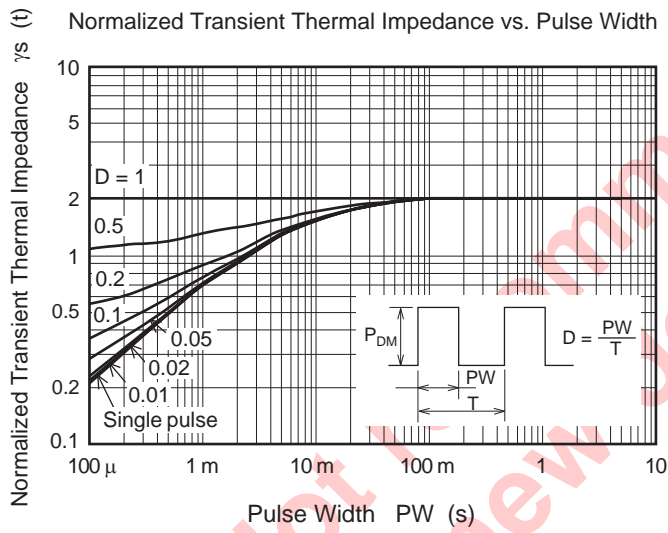
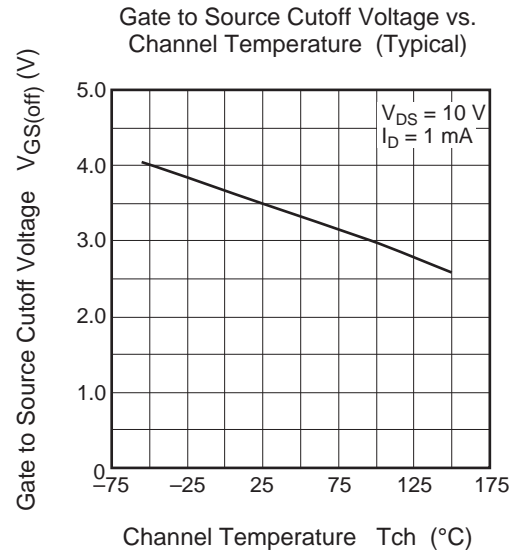
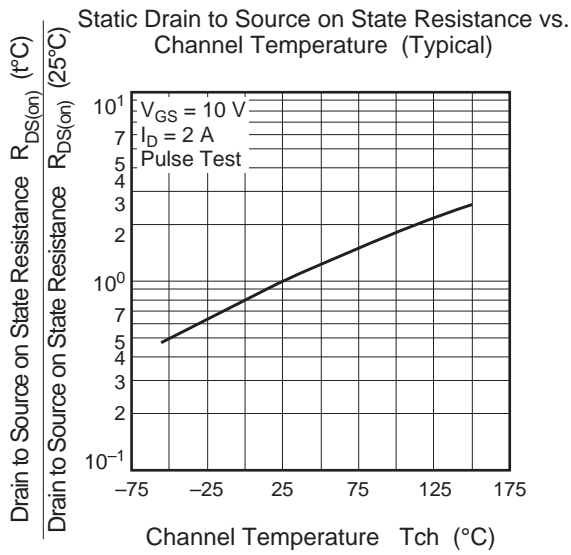


Reverse Drain Current vs. Source to Drain Voltage Characteristics (Typical)

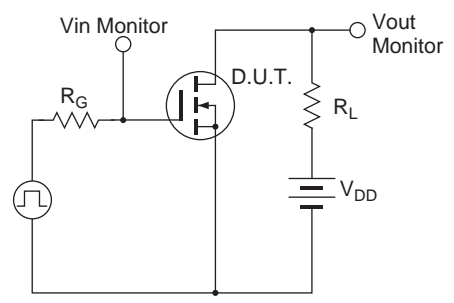


Breakdown Voltage vs. Channel Temperature (Typical)

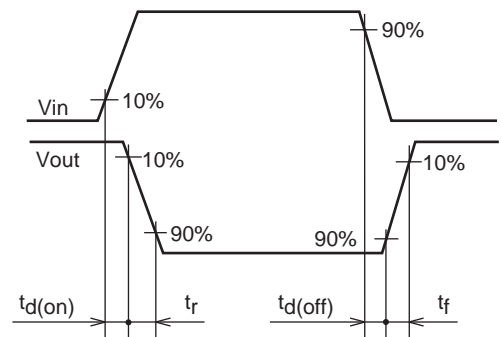




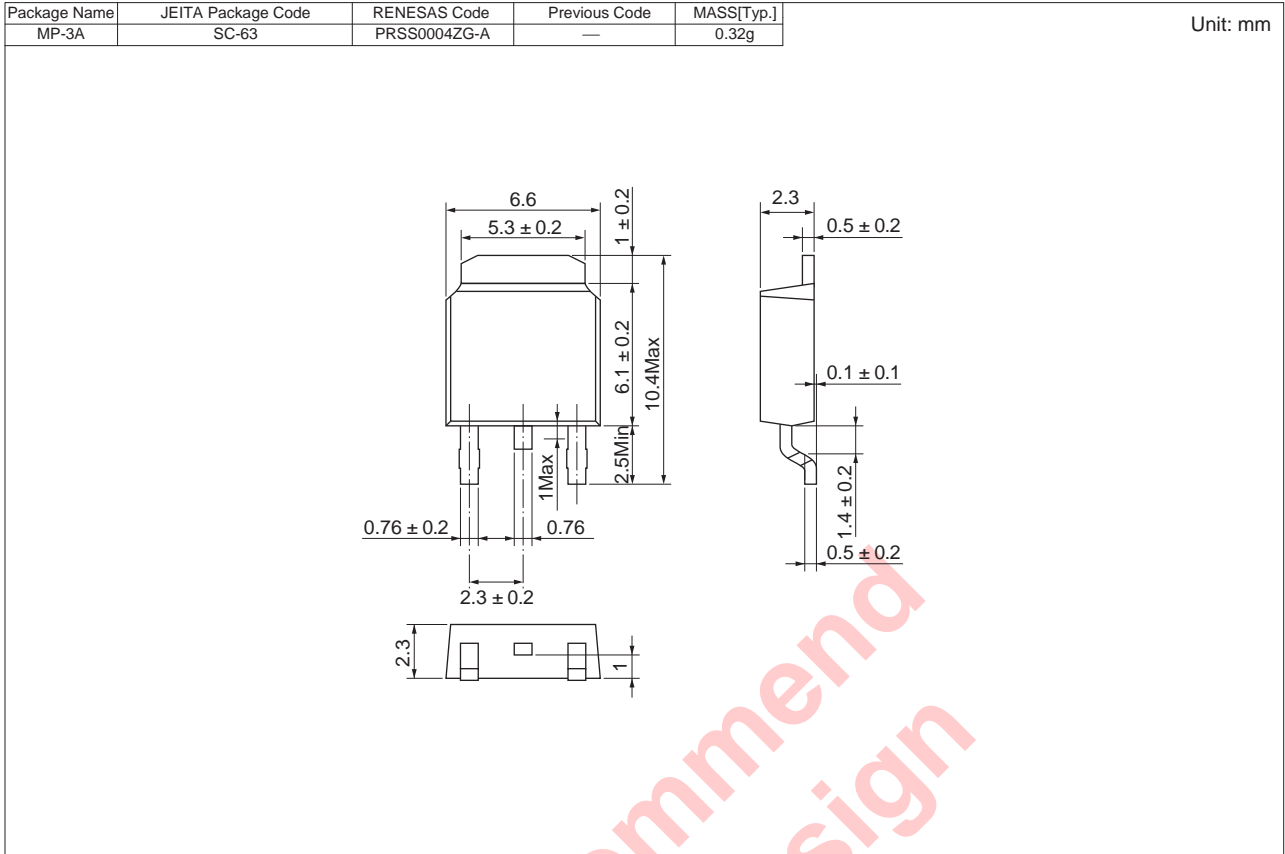
Switching Time Measurement Circuit



Switching Waveform



Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
RJK5003DPD-00-J2	3000 pcs	Taping

Not recommended for new design

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